

Sensor development for the LHCb VELO upgrade

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on behalf of the LHCb Velo upgrade group

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devices for very high luminosity colliders
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Outline

LHCb experiment

Current detector

Upgrade

LHCb upgrade

VELO upgrade

Test beam

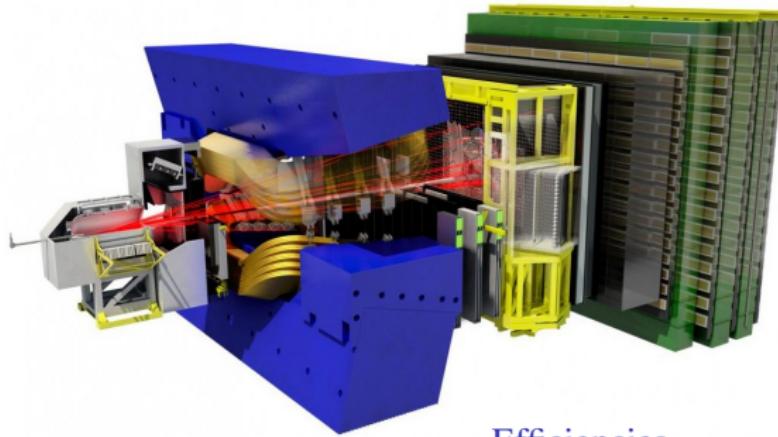
TPx3 telescope

Results

Conclusions

The LHCb experiment

LHCb is a forward spectrometer designed to study flavor physics exploiting the enormous production cross sections of heavy hadrons at the LHC



Characteristics

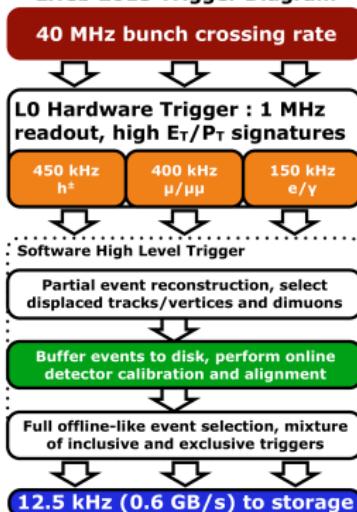
- Built for $\mathcal{L} = 2 \times 10^{32} \text{ cm}^{-2} \text{s}^{-1}$ at 25 ns spacing, with an average of $\mu = 0.4$ interactions per bunch crossing
 - In 2012 it ran at a $\mathcal{L} = 4 \times 10^{32} \text{ cm}^{-2} \text{s}^{-1}$ at 50 ns spacing with $\mu = 1.4$
 - Has recorded 1.1 fb^{-1} in 2011 and 2.1 fb^{-1} in 2012

Efficiencies

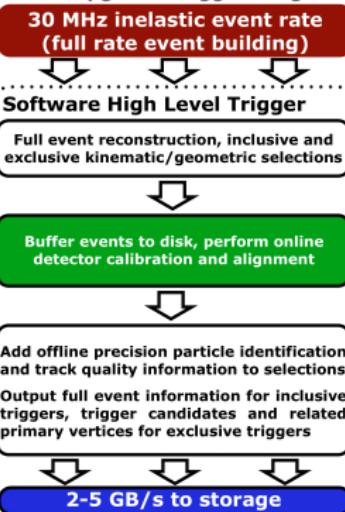
- All detectors with $>\sim 99\%$ active channels
 - $\epsilon(\text{operation}) > 94\%$
 - $\sim 98\%$ are good data

LHCb upgrade

LHCb 2015 Trigger Diagram



LHCb Upgrade Trigger Diagram



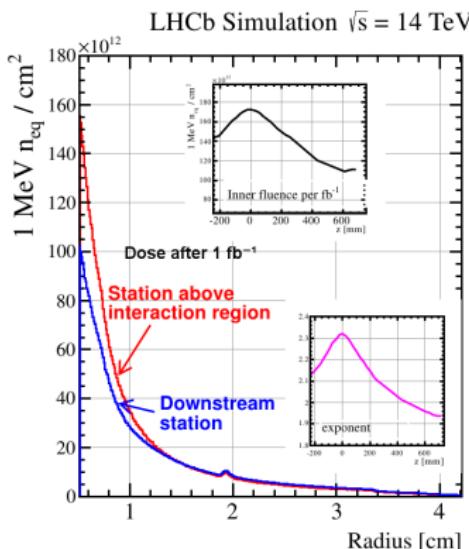
- Remove Hardware trigger. Use software-only trigger
- 1 to 30 MHz trigger rate
- Output rate from 12.5 to 100 kHz
- Increase luminosity to $\geq 2 \times 10^{33} \text{ cm}^{-2}\text{s}^{-1}$
- We aim to record 10 fb^{-1} per year

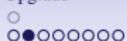
Apart from the increase in luminosity and trigger rate, we expect an increment of a factor 10 and 20 in the muonic and hadronic channels yield respectively

VELO upgrade

Requirements and challenges

- Data-driven readout at 40 MHz \Rightarrow up to 2.85 Tbit/s from whole VELO
- Radiation hardness at 8×10^{15} 1 MeV n_{eq} cm $^{-2}$.
Highly non-uniform radiation: $5.2 \times r^{-1.9}$ hits event $^{-1}$ cm $^{-2}$
- Keep/improve performance
- Increase granularity to allow operation at $\mathcal{L} \geq 2 \times 10^{33}$ cm $^{-2}$ s $^{-1}$
- Minimise material in acceptance
- Provide fast and robust track reconstruction (essential for software trigger)

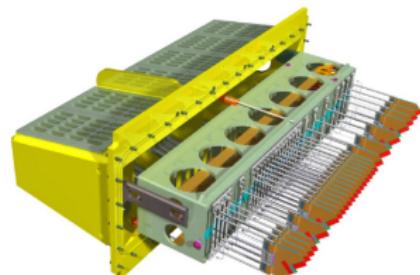
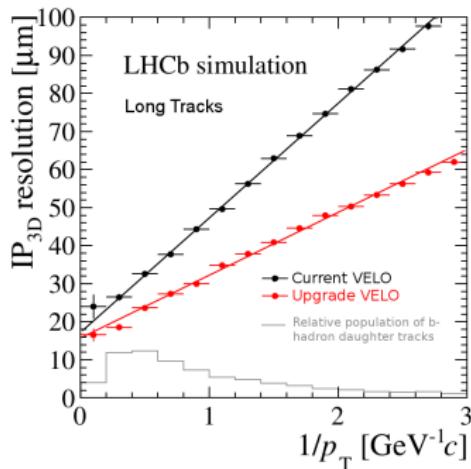
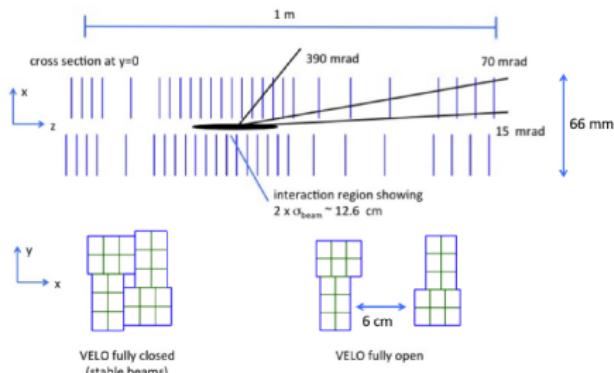




VELO upgrade

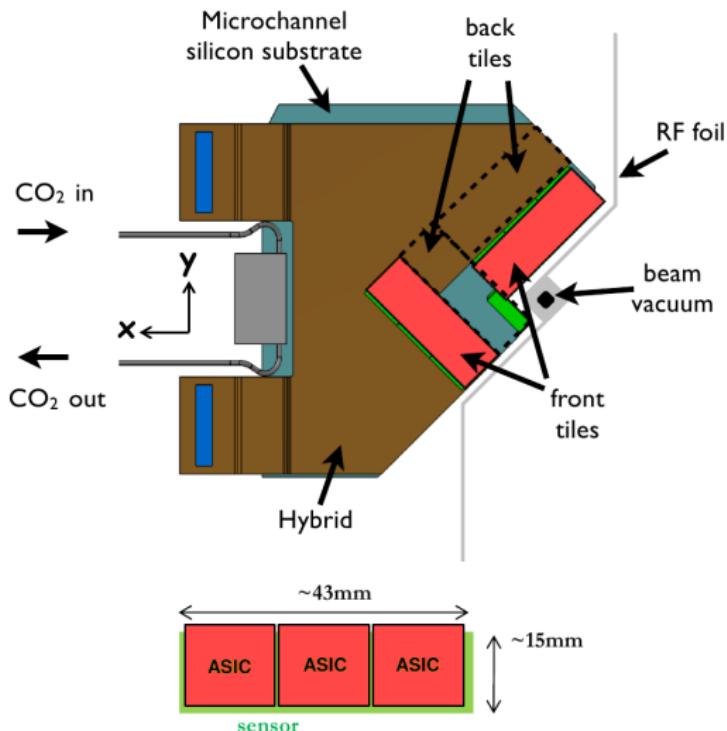
Characteristics of the new VELO

- From micro-strips to pixels
- Full detector consists of 26 stations (1 station = 2 modules, one on either side of the beam)
- Closest pixel is at 5.1 mm from the beam centre
- Separated from the beam vacuum by a $250 \mu\text{m}$ RF foil
- Geometrical efficiency $> 99\%$ for $R < 10 \text{ mm}$
- Track rate (and radiation damage) will be 10x higher



Modules

- 4 sensor tiles ($14 \times 42 \text{ mm}^2$), 2 on each side of substrate
- Each tile is bump bonded to 3 ASIC for readout
- Silicon substrate with integrated micro-channels for cooling
- Material in active region $\sim 0.9\% X_0$

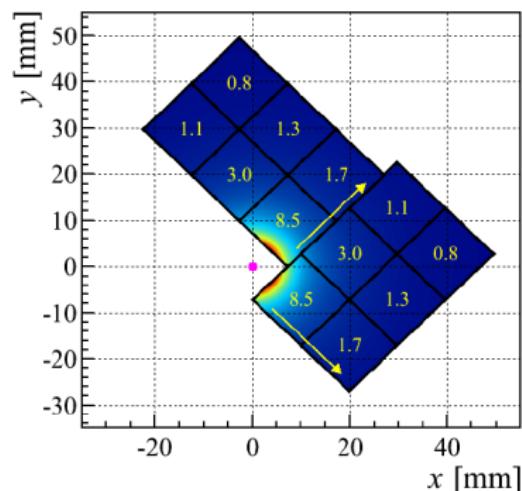
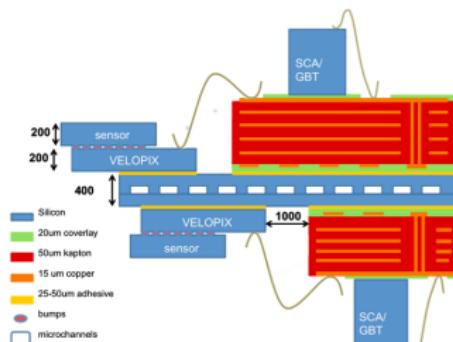


ASIC

Velopix

The upgraded VELO will be based on Velopix ASIC (successor of Timepix3) $55\text{ }\mu\text{m} \times 55\text{ }\mu\text{m}$ pixel size, 256×256 matrix

- Binary readout
- Hit rate up to 900 MHits/s. (Above 15.1 Gbit/s)
- Data driven readout: each hit is time-stamped, labeled and sent off chip immediately in a superpixel structure
- Radiation hard up to 400 MRad
- Submission planned for 2015 Q4

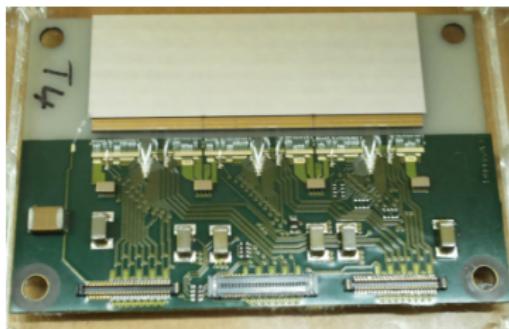


Mean number of particles crossing an ASIC per event

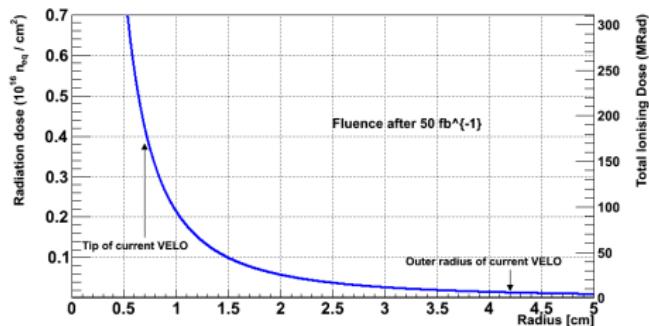


Silicon sensors

- Planar silicon n-in-p (evaluating n-in-n)
- Tile for 3 VeloPix chips: $\sim 43 \text{ mm} \times 14 \text{ mm}$, thickness $200 \mu\text{m}$
- $55 \mu\text{m} \times 55 \mu\text{m}$ pixel size
- $110 \mu\text{m}$ gap between ASICs bridged by elongated pixel implants
- Non homogeneous irradiation sets constraints on guard ring design
 - factor ~ 140 difference in fluence from tip to far corner
 - bias voltage at end on life ~ 1000 Volts for tip
 - guard ring width $\sim 450 \mu\text{m}$



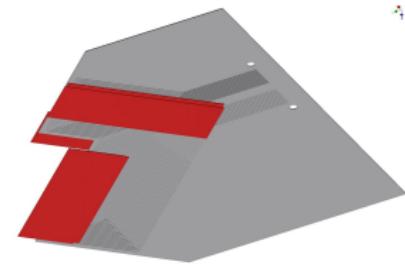
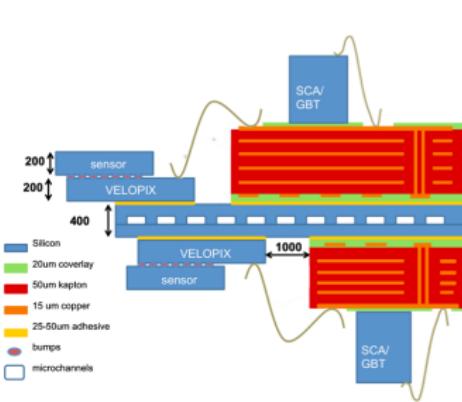
Sensor tile on a hybrid board



Hamamatsu prototype sensor

Cooling

- High speed pixel readout chips produce a lot of heat ($\sim 1.5 \text{ W/cm}^2$)
- Keep the sensors at $< -20^\circ\text{C}$ to minimize the effects of radiation damage, and to avoid thermal runaway
- Novel method: evaporate CO_2 via micro-channels etched in Si substrate
- Bring the cooling power where you need it, using least material
- No CTE difference (Si on Si)

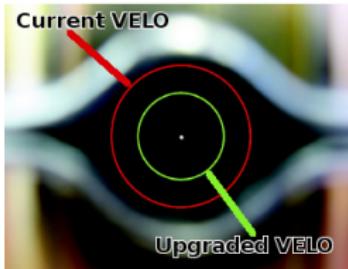


RF foil

The RF foil is a *de facto* beam pipe

Severe requirements:

- Vacuum tight ($< 10^{-9}$ mbar l/s)
- Radiation hard
- Low mass but mechanically stable
- Good electrical conductivity to mirror beam currents and shield against RF noise pick-up in FE electronics
- Thermally stable and conductive (heat load from the beam)



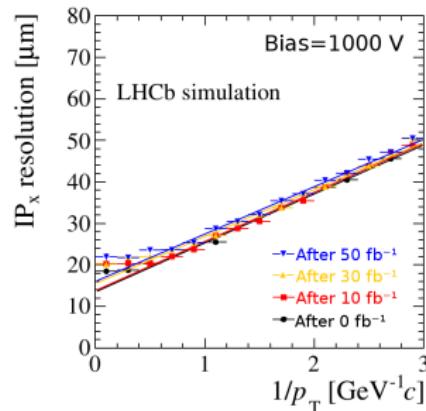
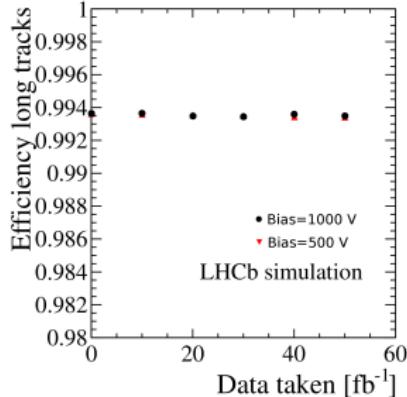
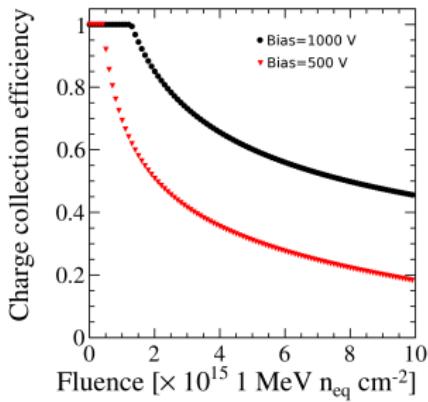
Sample with central part thinned to 150 μm

Material and fabrication:



- Mill foil from solid Al alloy block
- Achieve 250 μm thickness
- Chemical thinning being investigated to reduce the central part

Expected performance after irradiation



Charge collection efficiency decreases with radiation damage, but this effect is not propagated to the track reconstruction efficiency and the IP resolution

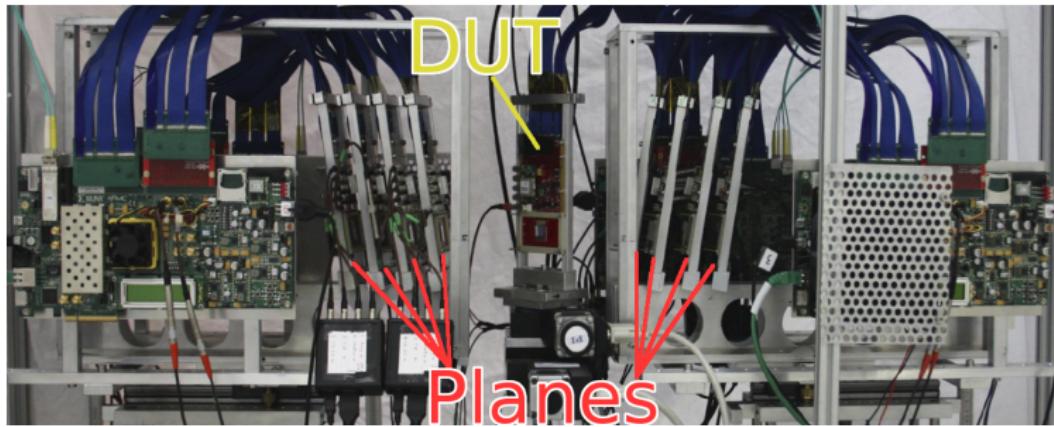
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Test beam

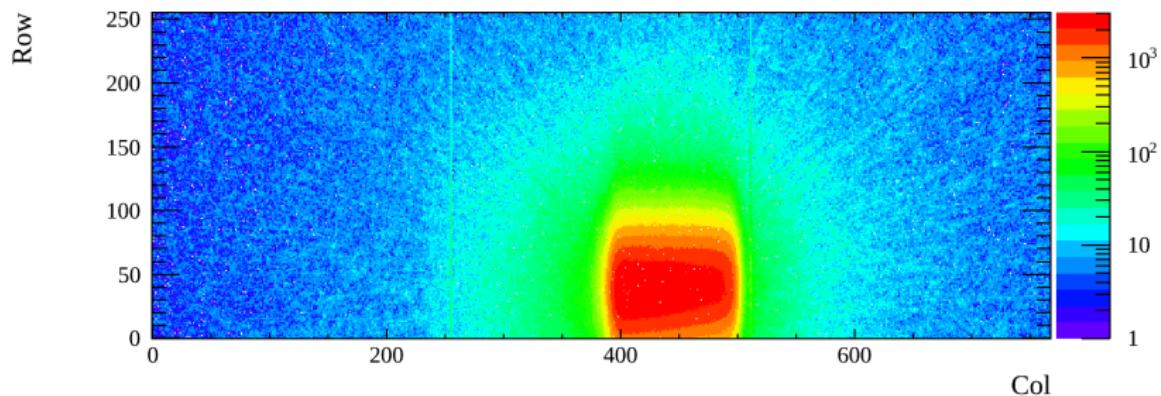
TimePix3 telescope

- 8 planes divided in two arms
- Each plane consist in a Timepix3 chip bump bonded to a $300\ \mu\text{m}$ $p\text{-on-}n$ Si sensor
- Track rate > 5 MHz. Only limited by beam intensity
- Resolution at the DUT plane $2\ \mu\text{m}$ (with $180\ \text{GeV}/c$ π beam)
- $1.4 \times 1.4\ \text{cm}^2$ of active area
- Data driven readout



Test beam

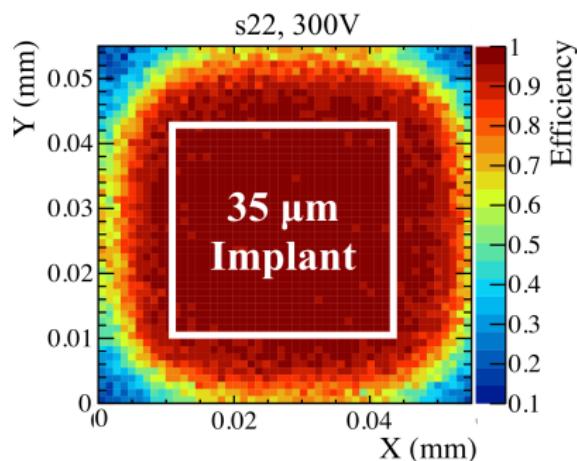
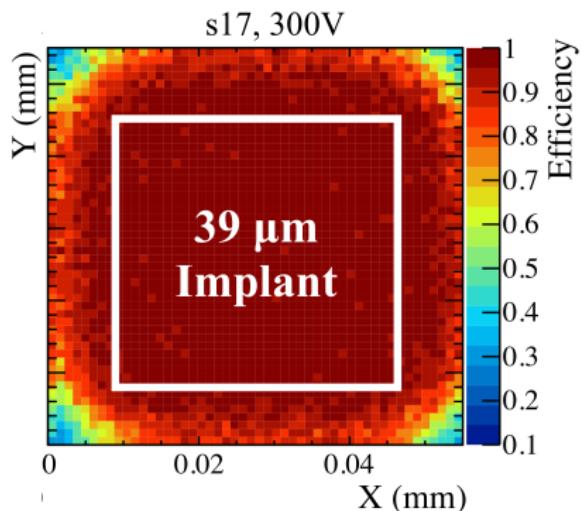
200 μm thick Hamamatsu 3 \times 1 tile on 3 Timepix3 chips bump-bonded by Advacam



Hit map of a 3 \times 1 tile in a 180 GeV SPS beam

Test beam

Interpixel efficiencies



Both sensors tested are:

- Manufactured by HPK
- 200 μm *n-on-p*
- Bias -300 V
- Irradiated homogeneously to $8 \times 10^{15} 1 \text{ MeV n}_{\text{eq}} \text{ cm}^{-2}$

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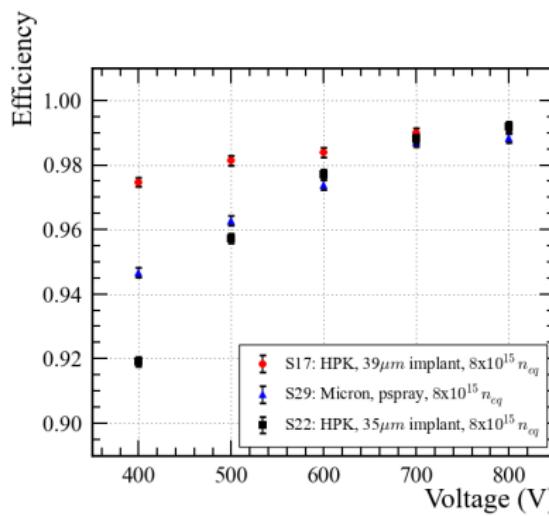
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Test beam

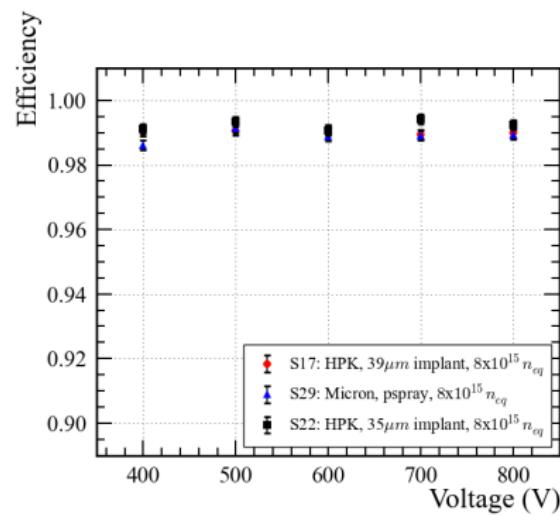
Sensors tested

- 2 sensors from HPK: $200\text{ }\mu\text{m }n\text{-on-}p$
- 1 sensor from Micron: $150\text{ }\mu\text{m }n\text{-on-}n$. $36\text{ }\mu\text{m}$ implants

Interpixel corners efficiency

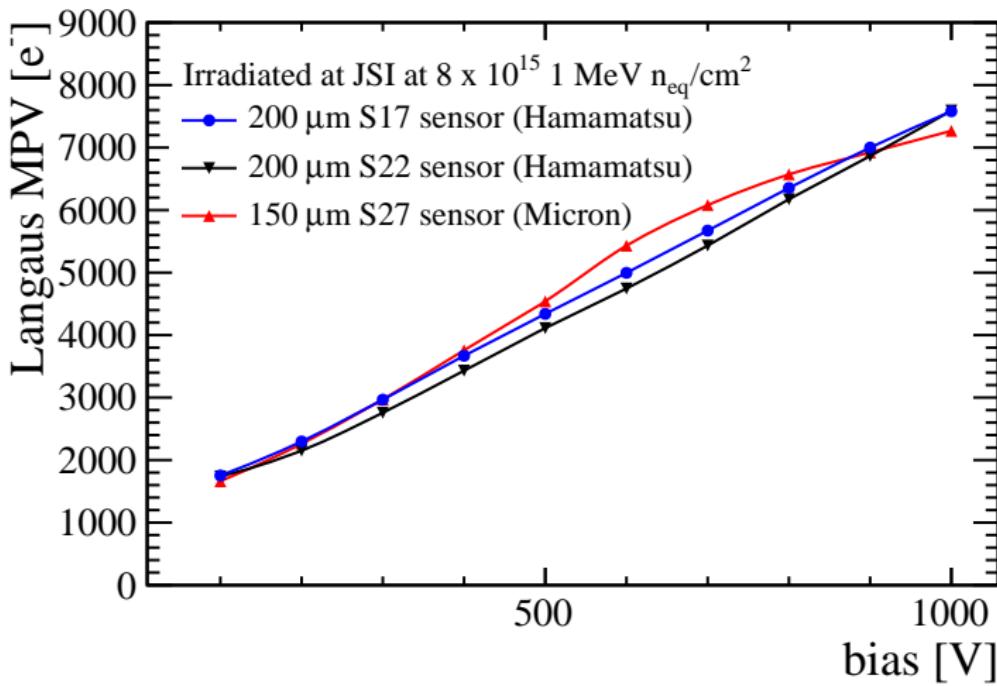


Interpixel centre efficiency



Test beam

Charge collection efficiency



Conclusions

The requirements for the LHCb VELO upgrade are very demanding:

- Luminosity will be increased by a factor ≥ 5
- Keep or improve the performance of the current VELO

Upgrade VELO characteristics:

- Vertex Locator will consist of planar silicon pixels, $55 \times 55 \mu\text{m}^2$
- The first pixel will be only at 5.1 mm from the beam axis
- Evaporative CO₂ cooling in Silicon micro-channel substrate
- Material budget reduction in elements placed in the acceptance (modules, RF-Foil)

Still a lot of work to do:

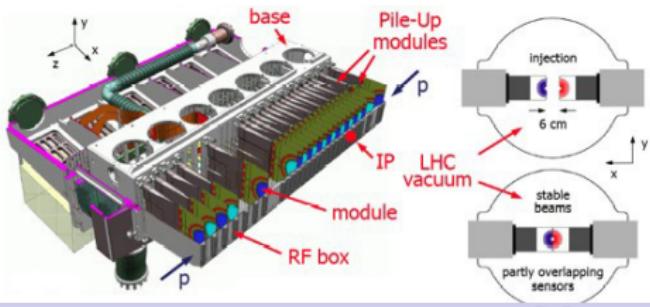
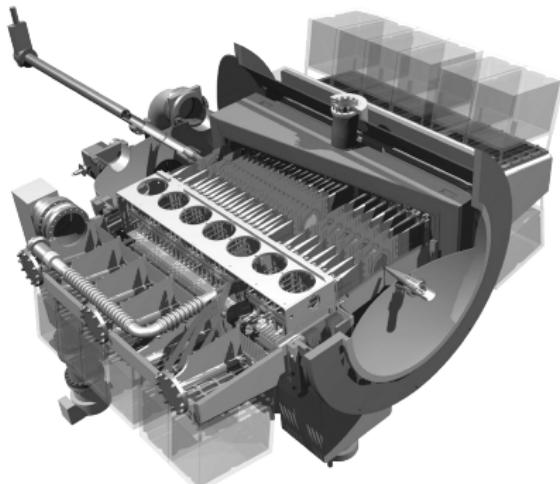
- Intense testbeam program to validate: sensor technologies, radiation hardness, cooling schemes and readout electronics
- Sensor, electronics, modules and mechanics production

Installation during long shutdown 2 in 2019

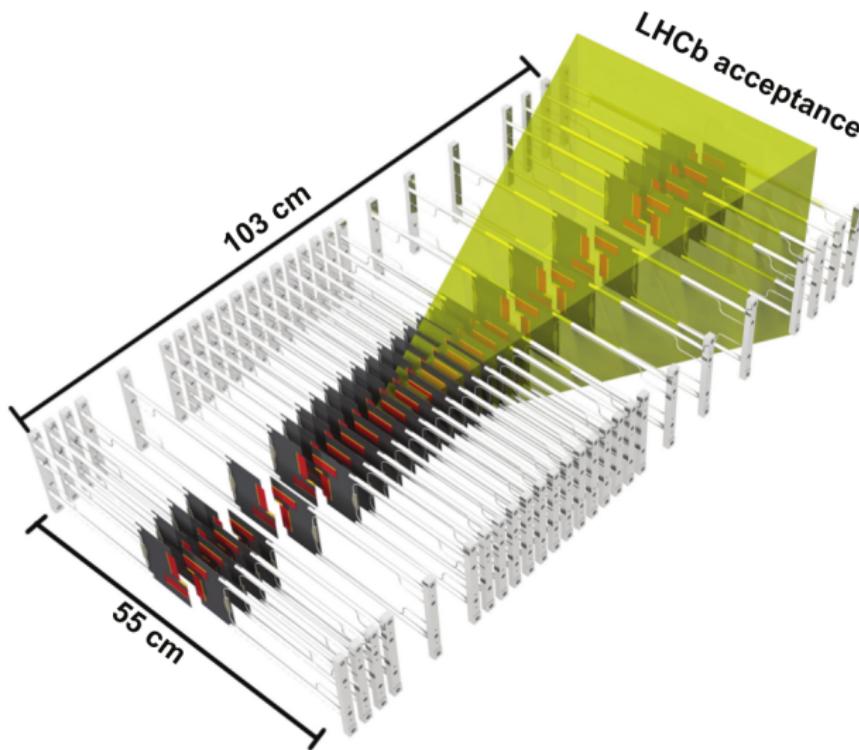
Backup

The Vertex Locator (VELO)

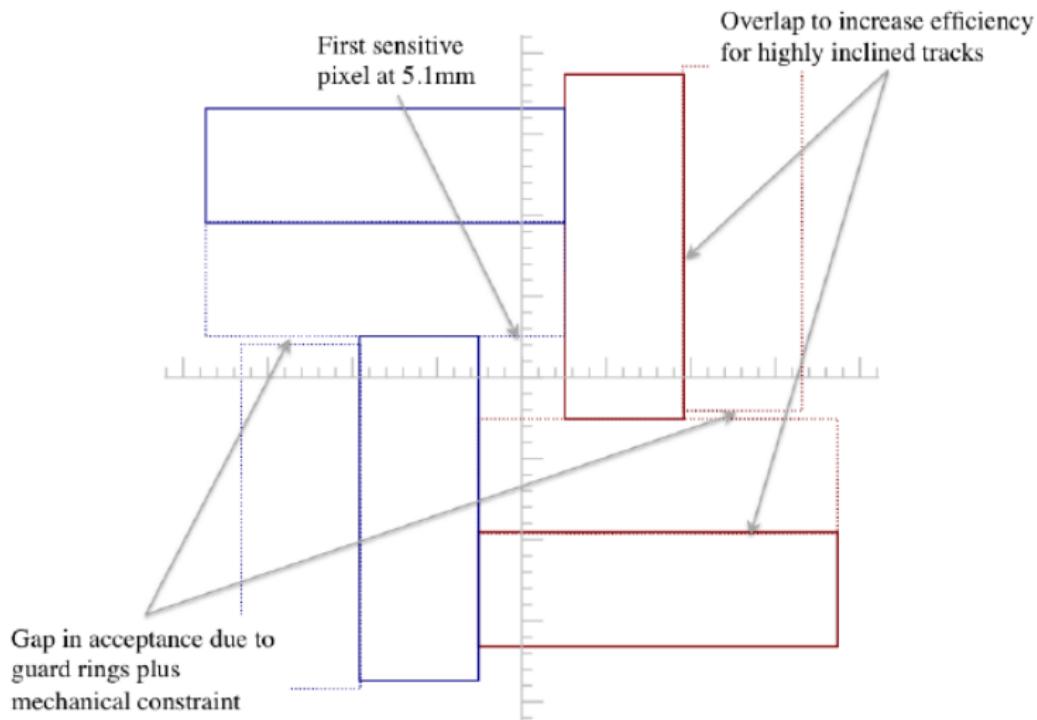
- Silicon strip detector surrounding the interaction point
- 88 silicon n^+ -on-n sensors, 300 μm thick, R- ϕ design
- Located only 8 mm from the beams
- Enclosed into a separated vacuum box (RF Foil)
- Halves are separated for beams injection
- 1 MHz trigger rate
- Bi-phase CO₂ cooling system



Backup

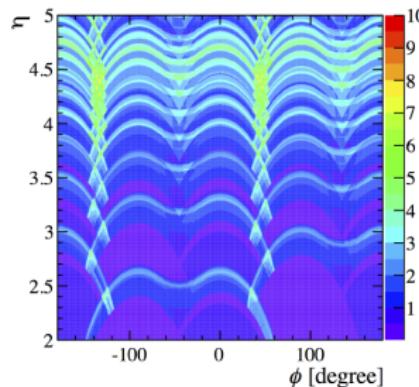
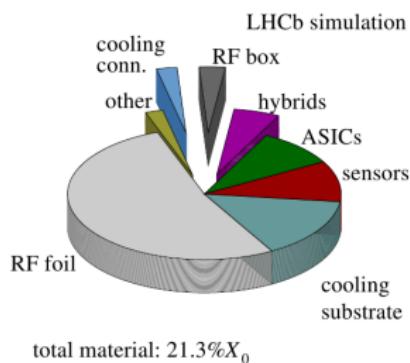
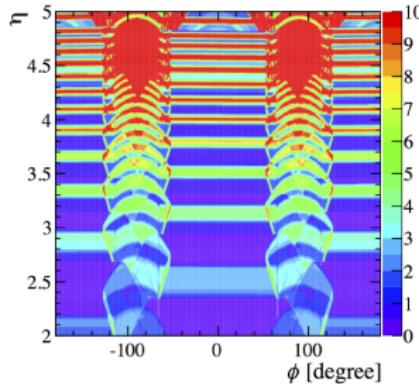
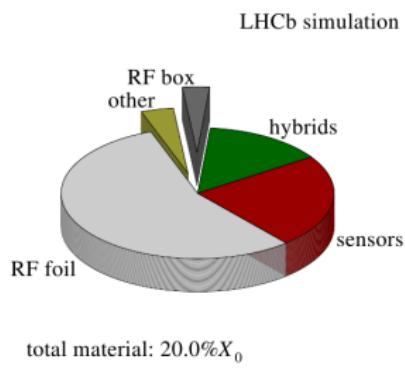


Backup





Backup

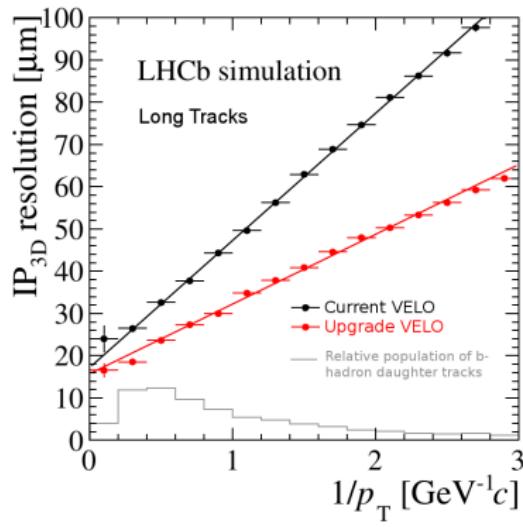


Backup

$$\sigma_{\text{IP}}^2 = \frac{r_1^2}{p_T^2 \sqrt{2}} \left(0.0136 \sqrt{\frac{x}{X_0}} \left(1 + 0.038 \ln \left(\frac{x}{X_0} \right) \right) \right)^2 + \frac{\Delta_{02}^2 \sigma_1^2 + \Delta_{01}^2 \sigma_2^2}{\Delta_{12}^2}$$

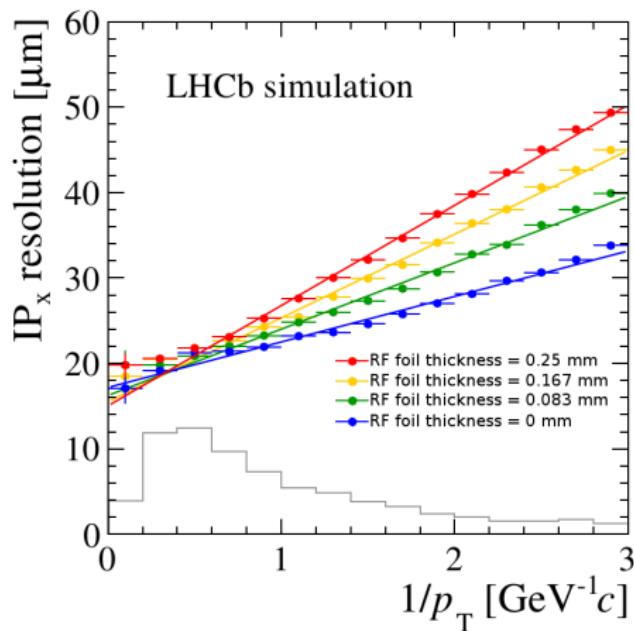
Comparison between current and upgraded VELO

- A smaller RF foil inner radius (3.5 versus 5.5 mm)
- A smaller inner edge distance to the beams for the sensitive part; $R_{det} \sim 5.1$ mm versus 8 mm
- A coarser inner pitch ($p = 55 \mu\text{m}$ pixels versus $40 \mu\text{m}$ strips)
- A smaller Si thickness ($t_{det} + t_{ASIC} = 0.4$ versus $t_{det} = 0.6$ mm for an R-phi station)
- A smaller z distance between stations ($\Delta z = 25$ versus 30 mm)



Backup

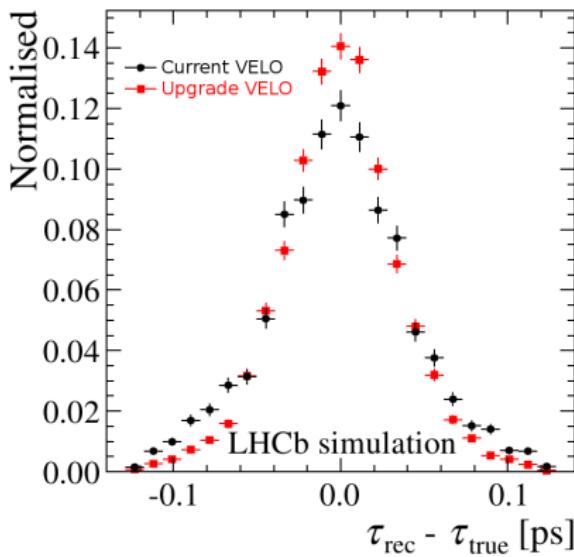
Expected performance (IP resolution)



Impact parameter resolution in x for the upgrade VELO for the nominal RF foil thickness (0.25 mm) and three additional thicknesses.

Backup

Expected performance (τ and z resolutions)



Decay time for $B^0 \rightarrow K^{*0} \mu^+ \mu^-$ resolution

